



The Capacitance Company
KEMET
CHARGED.™

Capacitor Consortium Meeting
CU-ICAR
January 21, 2009

- **KEMET Background**
- **Some New Products**
 - ▶ Film and Electrolytic Capacitors for Green applications
 - ▶ Low Inductance Ta-Polymer For Decoupling Applications
 - ▶ High Voltage Tantalum-Polymer for Power Supply
 - ▶ 200°C Ceramics for Extreme Environments

KEMET Milestones



2007 Arcotronics acquisition

2007 Evox Rifa acquisition

2006 EPCOS tantalum business acquisition

2004 TS16949 Certification

2001 First Solid Aluminum Capacitors (AO-CAP)

1997 First Organic Polymer Capacitors (KO-CAP)

1997 QS-9000 Certification

1992 KEMET went public

1987 KEMET Electronics Corporation was formed by a management LBO

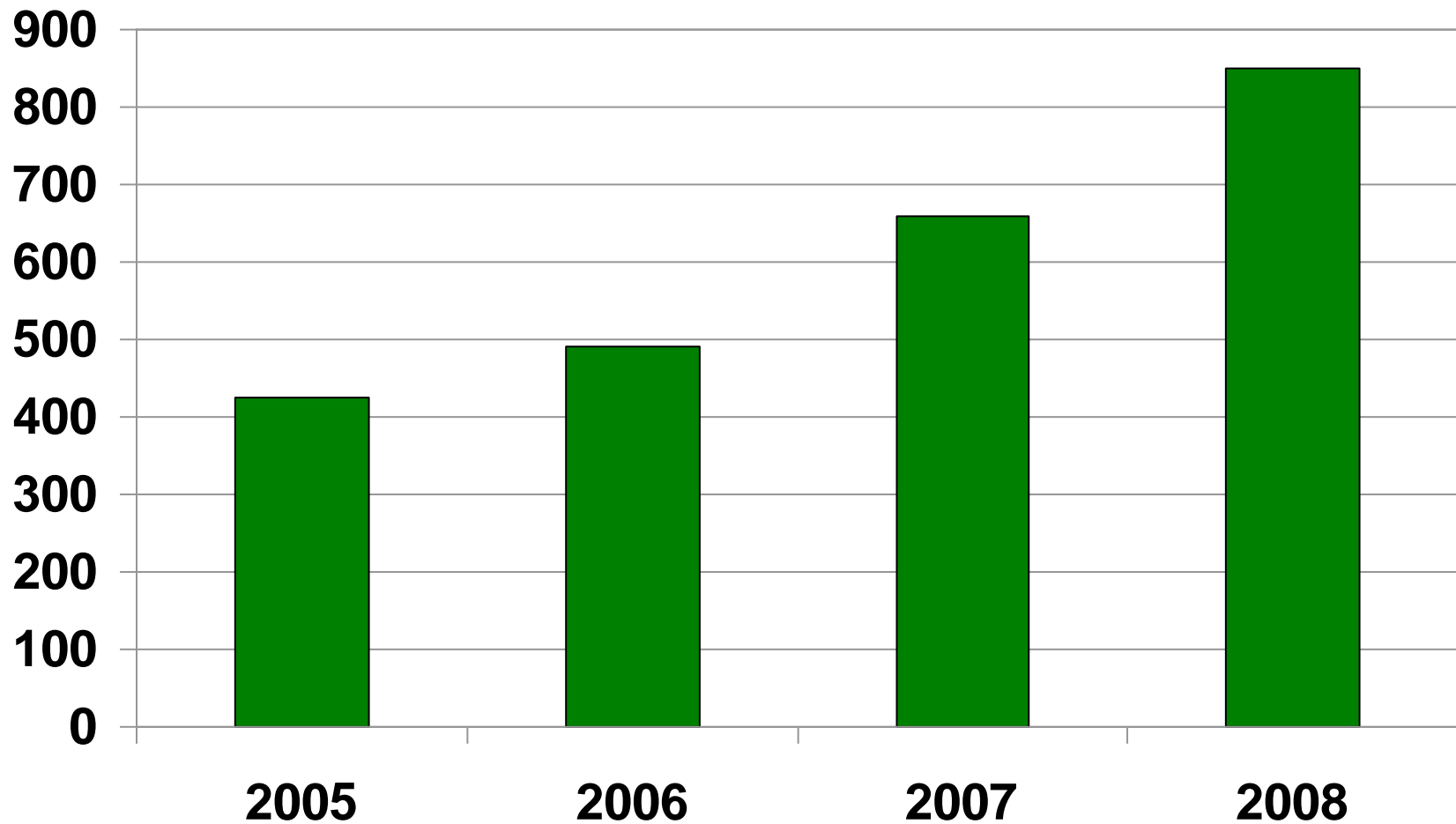
1950's Transistors and solid tantalum capacitors were invented by Bell Labs

1930 KEMET began manufacturing barium-aluminum alloy getters for use in vacuum tubes

1919 KEMET Laboratories was founded by Union Carbide

Sales

(\$ Millions)



Worldwide Locations



Greenville, SC USA



Weymouth, UK



Landsberg, Germany



Suomussalmi, Finland



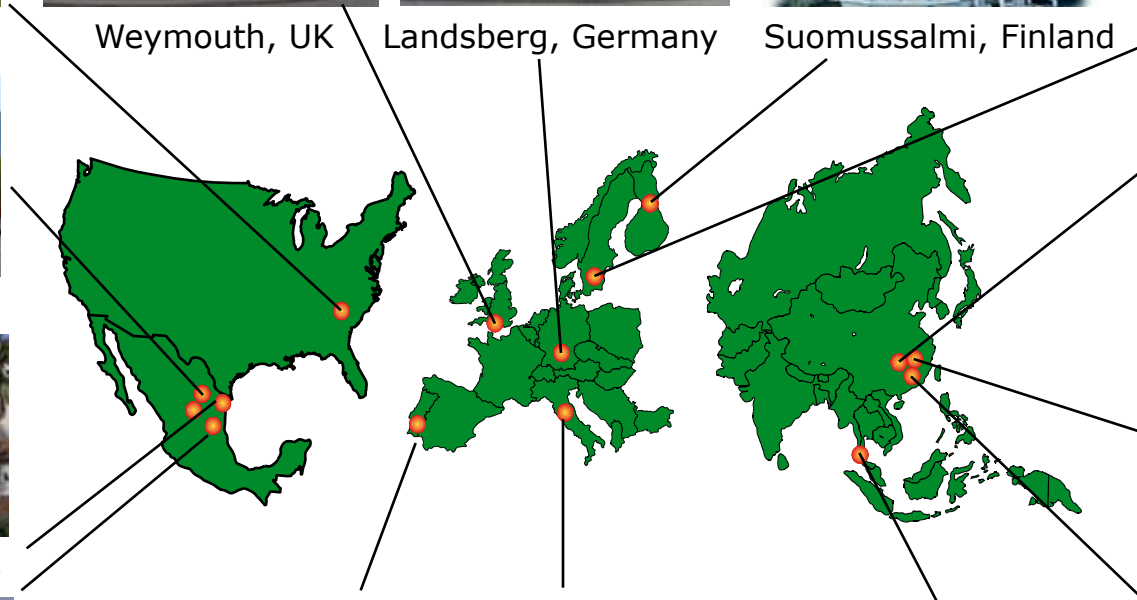
Granna, Sweden



Monterrey, Mexico



Matamoros, Mexico



Suzhou, China



Anting, China



Victoria, Mexico



Evora, Portugal



Bologna, Italy



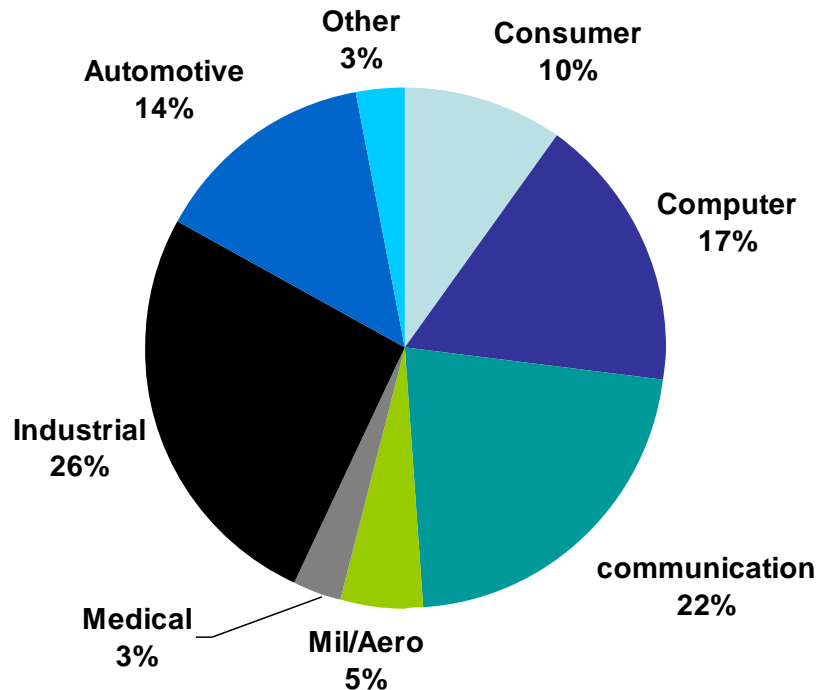
Batam, Indonesia



Nantong, China

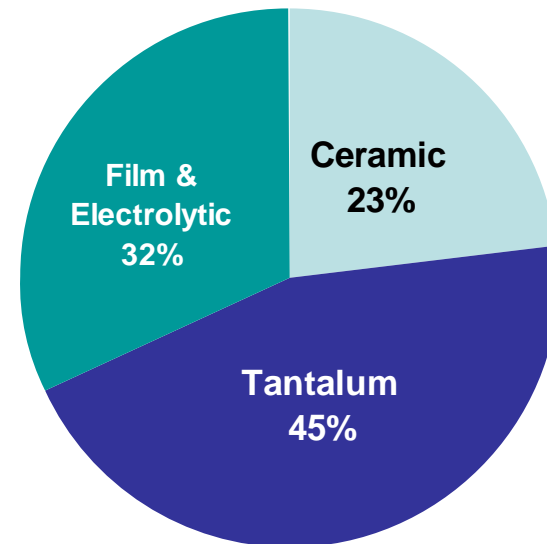
Balanced Business Mix: Market Segments and Products

End Markets



September 30, 2008

Product Lines

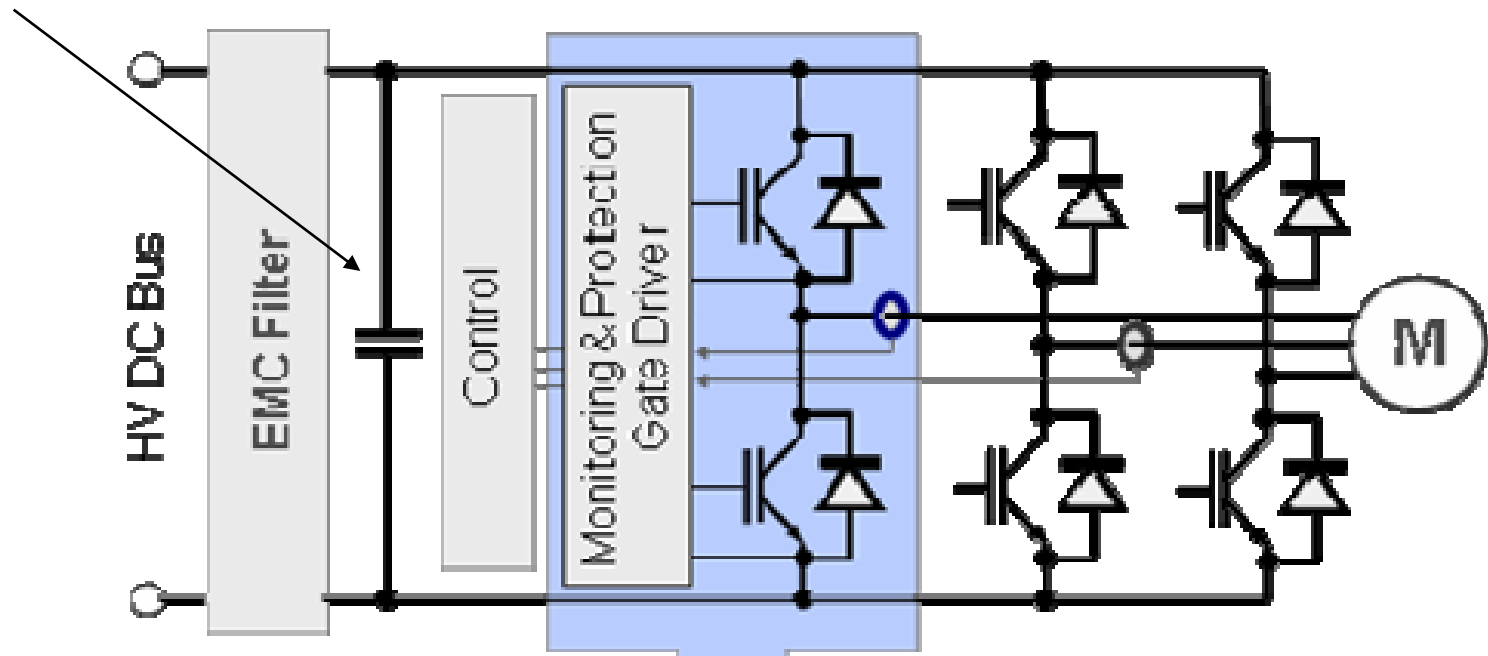


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Green Energy Applications



DC-Link Capacitor

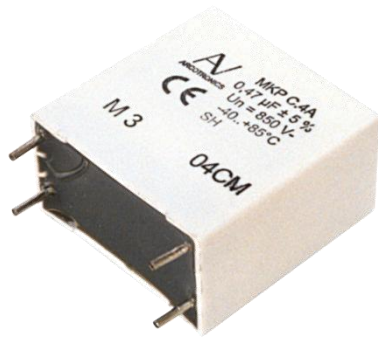


Power Capacitors for Green Applications

DC-Link and AC Filter



Small Film



For low power application.
PCB mounting
FOR SOLAR POWER
(several parallel in a bank)

Electrolytic



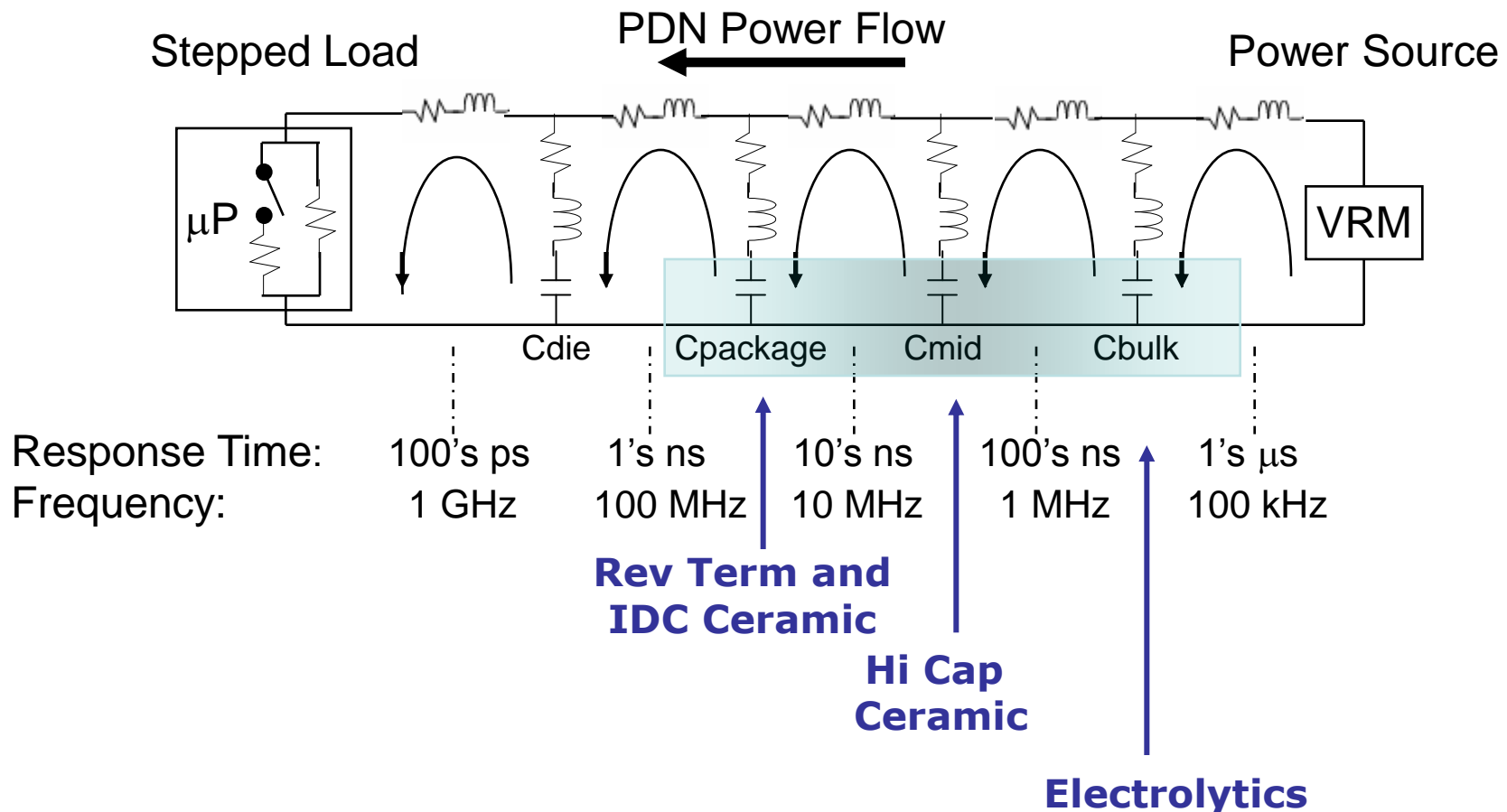
For medium/high power application.
For modular solution
FOR INDUSTRIAL OR WIND POWER

Large Brick Film

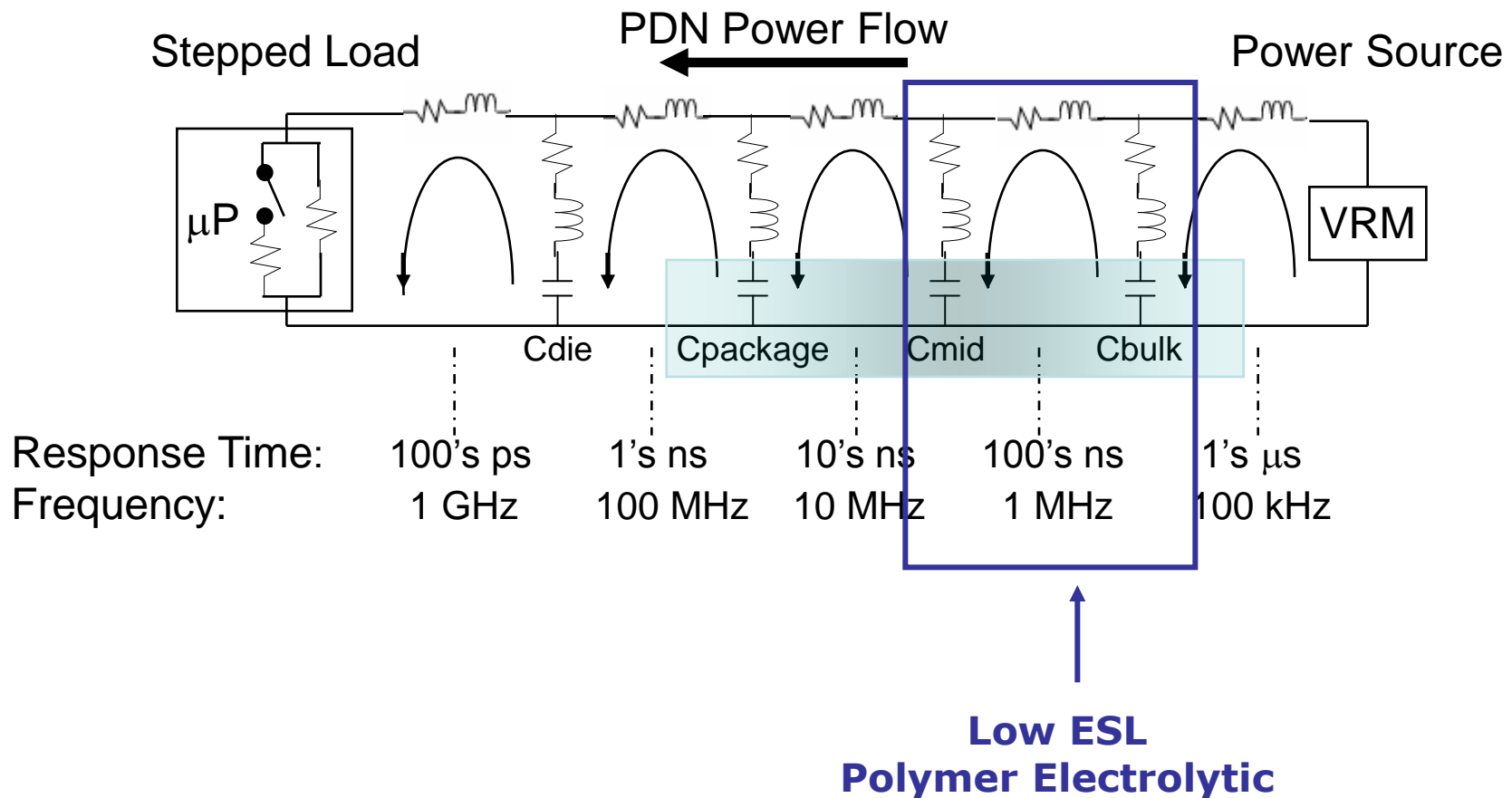


For medium/high power application.
FOR HYBRID AUTOMOBILE AND INDUSTRIAL POWER

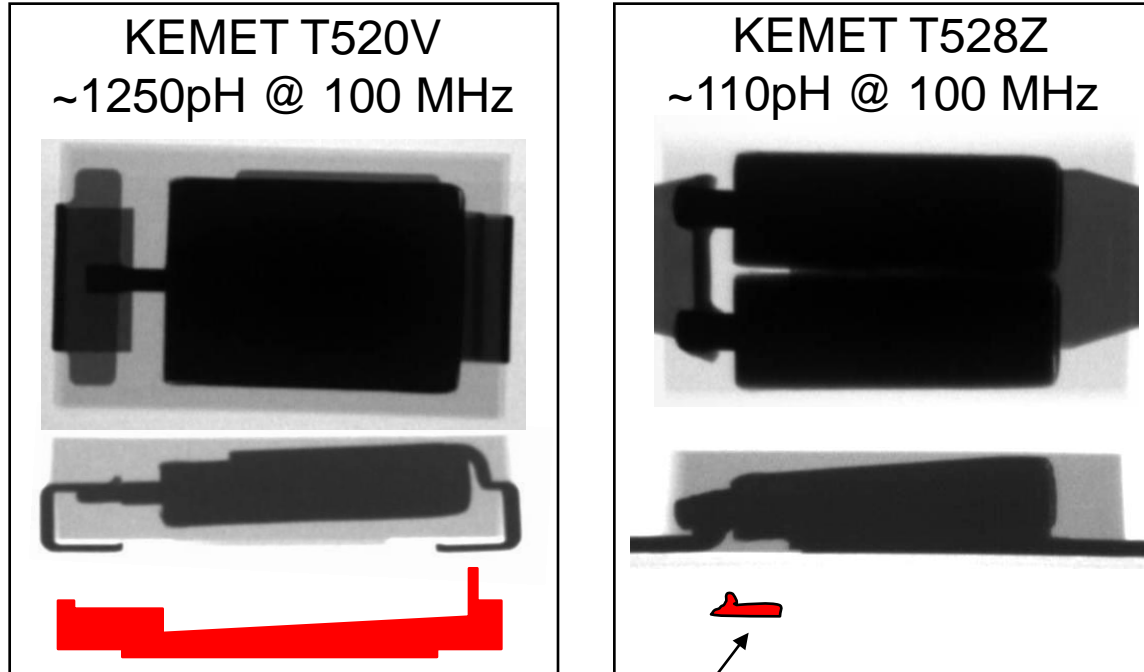
μ P Power Distribution Networks



μ P Power Distribution Networks

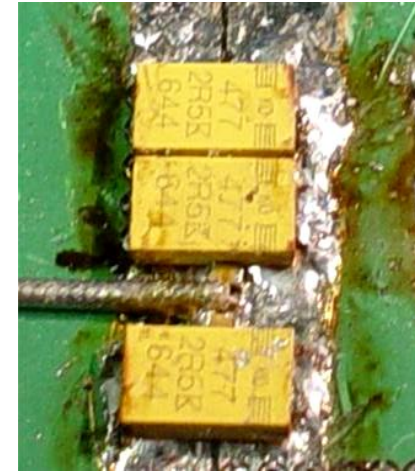
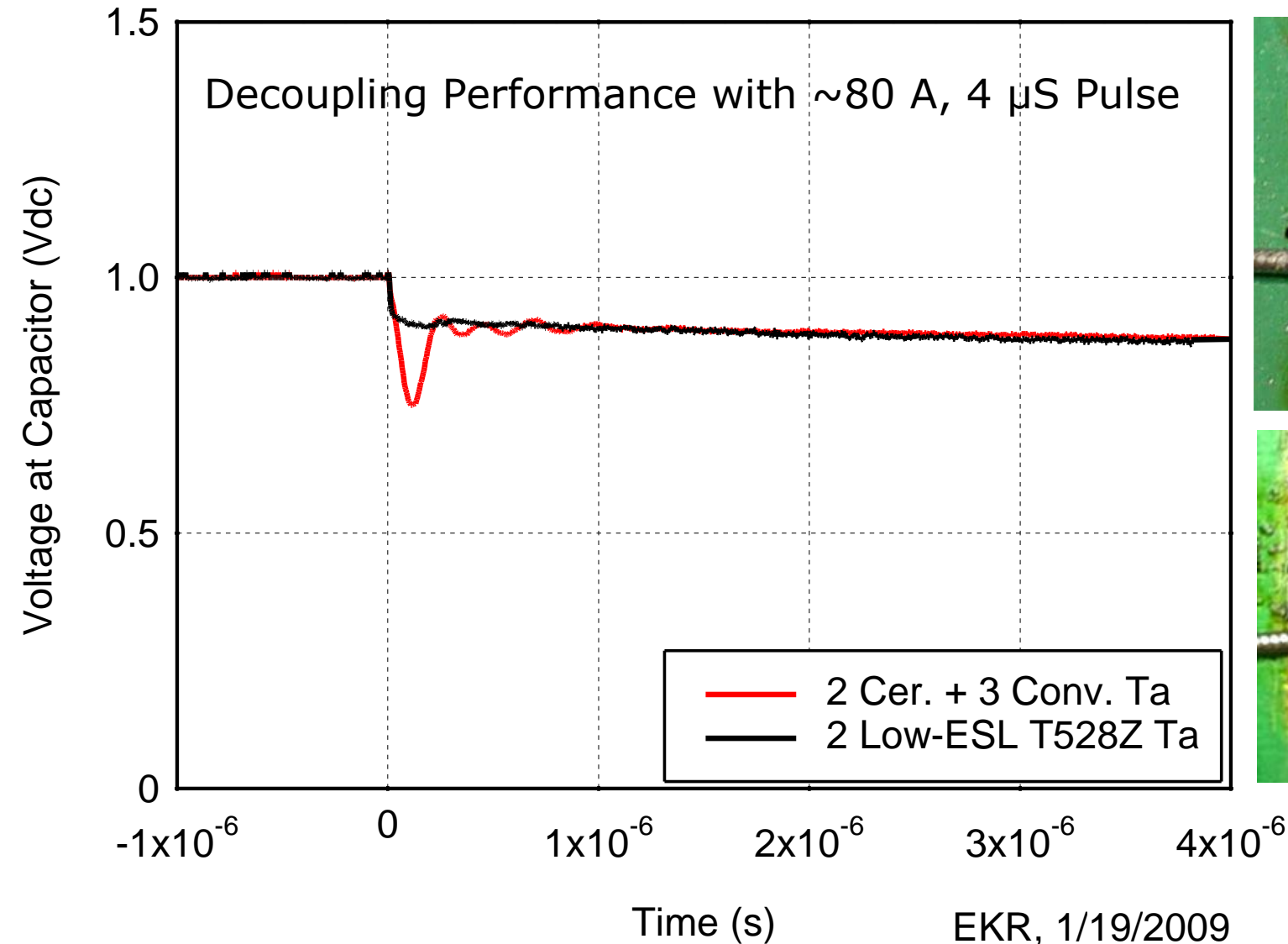


Comparison of Standard and Low ESL Construction

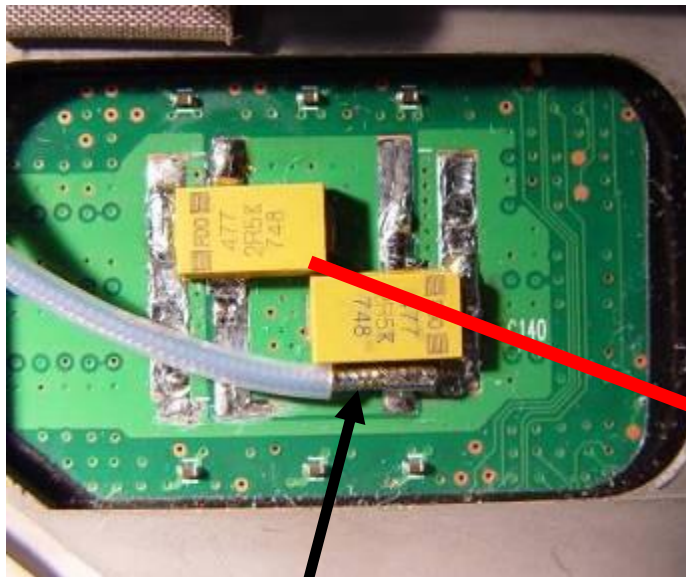


ESL is driven by loop area defined by the HF current path above the circuit board plane

Comparison of Standard and Low ESL Solutions



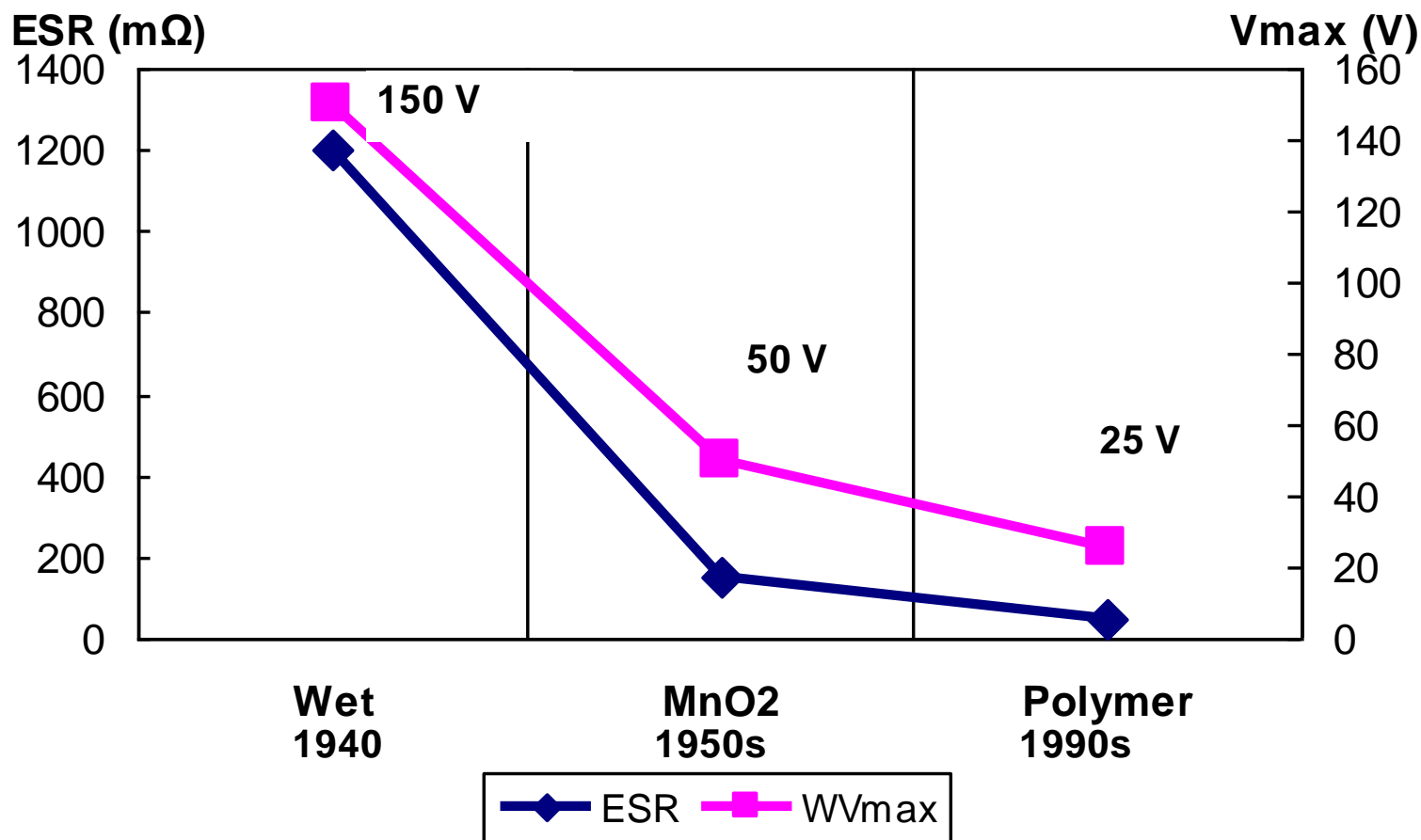
KEMET T528Z in Laptop with No Bulk Ceramics



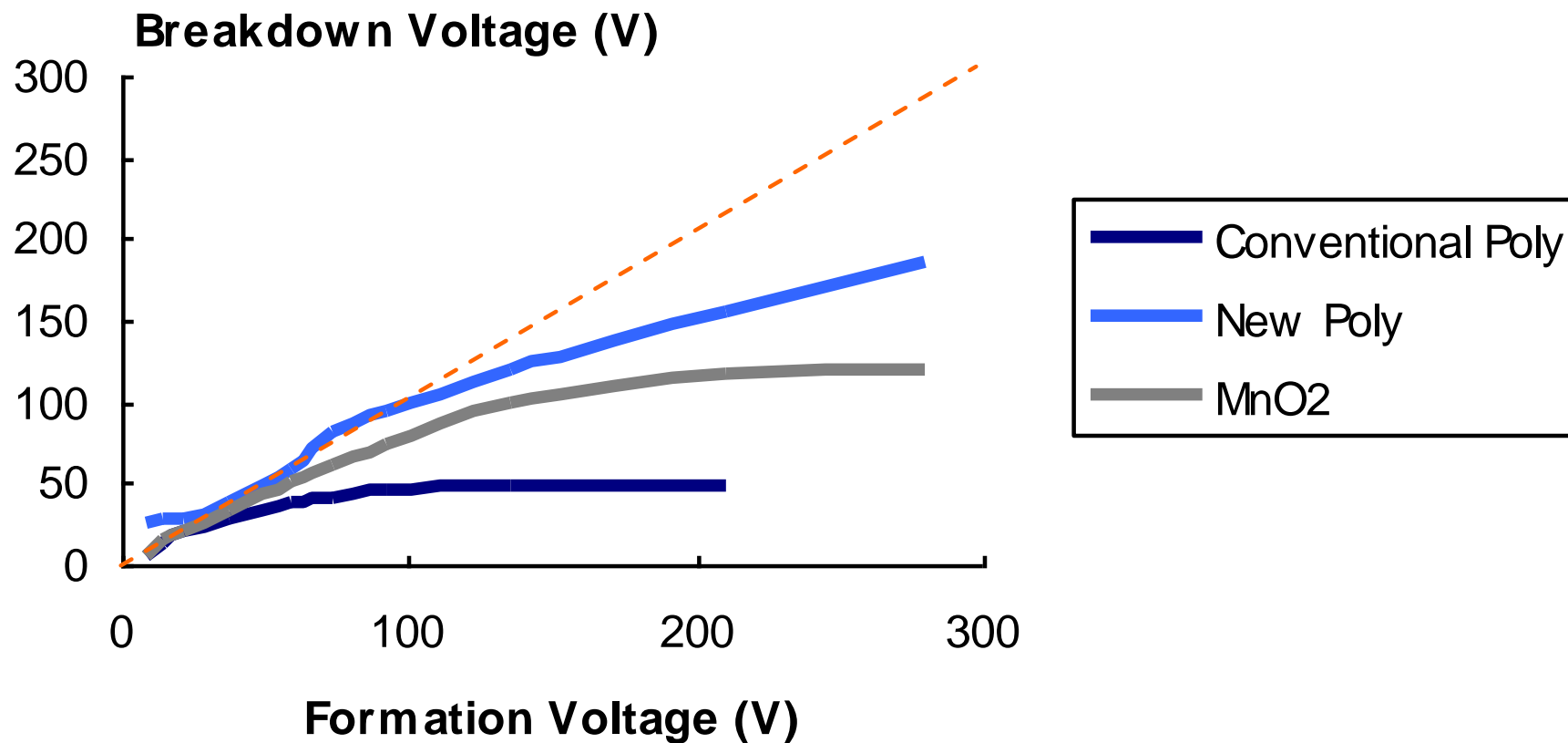
Voltage Probe



Progress in Tantalum Capacitors



Breakdown Voltage



KO High Voltage Product Development

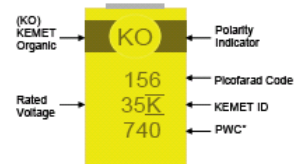


KEMET Introduces the First 35 Volt Rated Polymer Tantalum Capacitor

Component Dimensions and Case Codes

Case Codes			Component Dimensions (mm)				
KEMET	EIA		L	W	H	F ± 0.1	S ± 0.3
V	7343-20		7.3±0.3	4.3±0.3	1.9 max	2.4	1.3

Component Marking



Explanation of Part Number

<u>T521</u> Series	<u>V</u> Case Code	<u>156</u> Capacitance	<u>M</u> Capacitance Tolerance (M=20%)	<u>035</u> Voltage	<u>A</u> Failure Rate (A=Not Applicable)	<u>I</u> Termination Material (I = 100% Sn (H = 50%Sn/10%Pb))	<u>E125</u> Maximum ESR Limit (E125=125mΩ)
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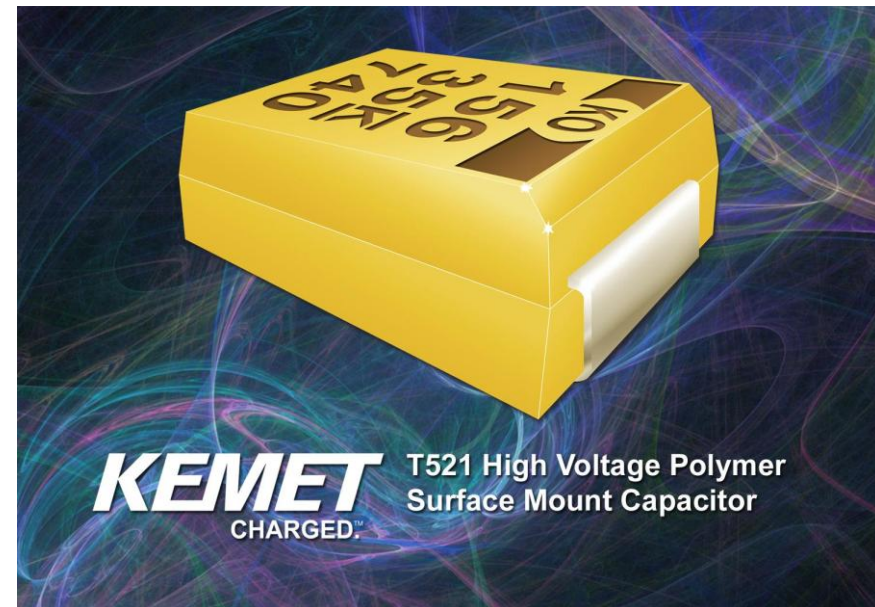
* 740 = 40th week of 2007

Part Number Specification

KEMET Part Number	KEMET Part Number	Cap (μF)	Voltage	DCL VR (μA)	DF 120Hz (%)	ESR 100KHz (mΩ)	Maximum allowable ripple current (mA rms) 100KHz*	MSL Reflow Temp 260°C
T521V156M035A(1)E125	V/7343-20	15	35	52.5	10	125	1200.0	3.0

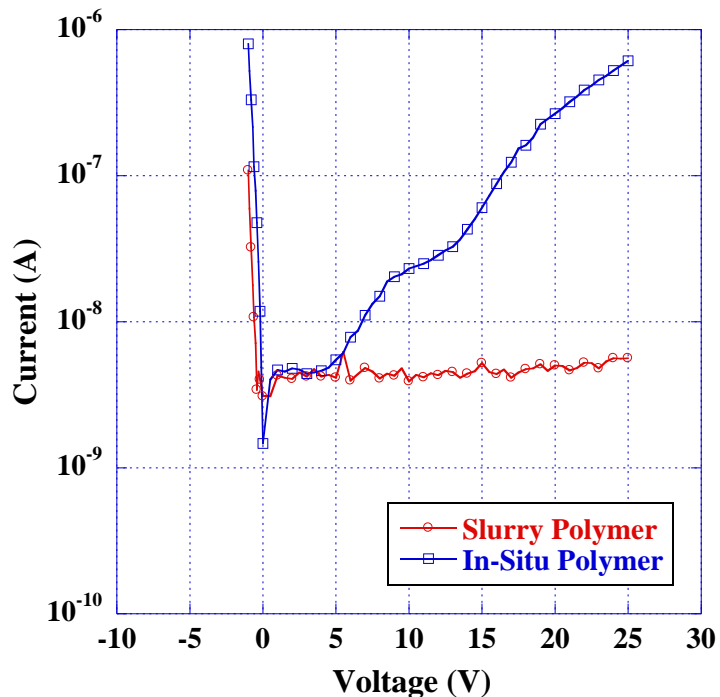
(1) To complete KEMET Part Number, insert letter designation for lead frame material

*100KHz to 500KHz, 45 °C





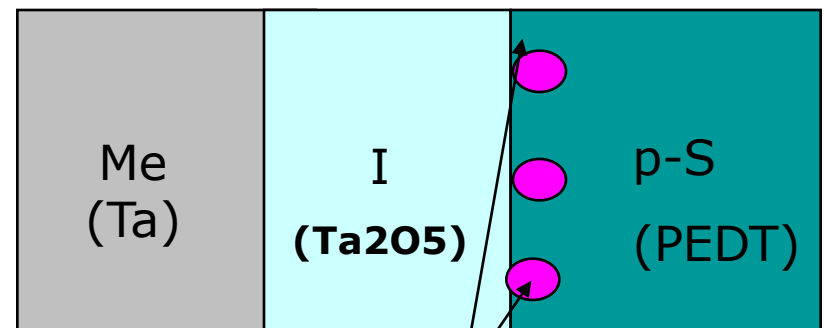
Slurry & In-Situ Polymer I-V @ T = 300K
Delay Time = 65 seconds



- Local charge forms in In-situ polymer on its interface with Ta Oxide during polymerization reaction, pinning the barrier on IS interface.

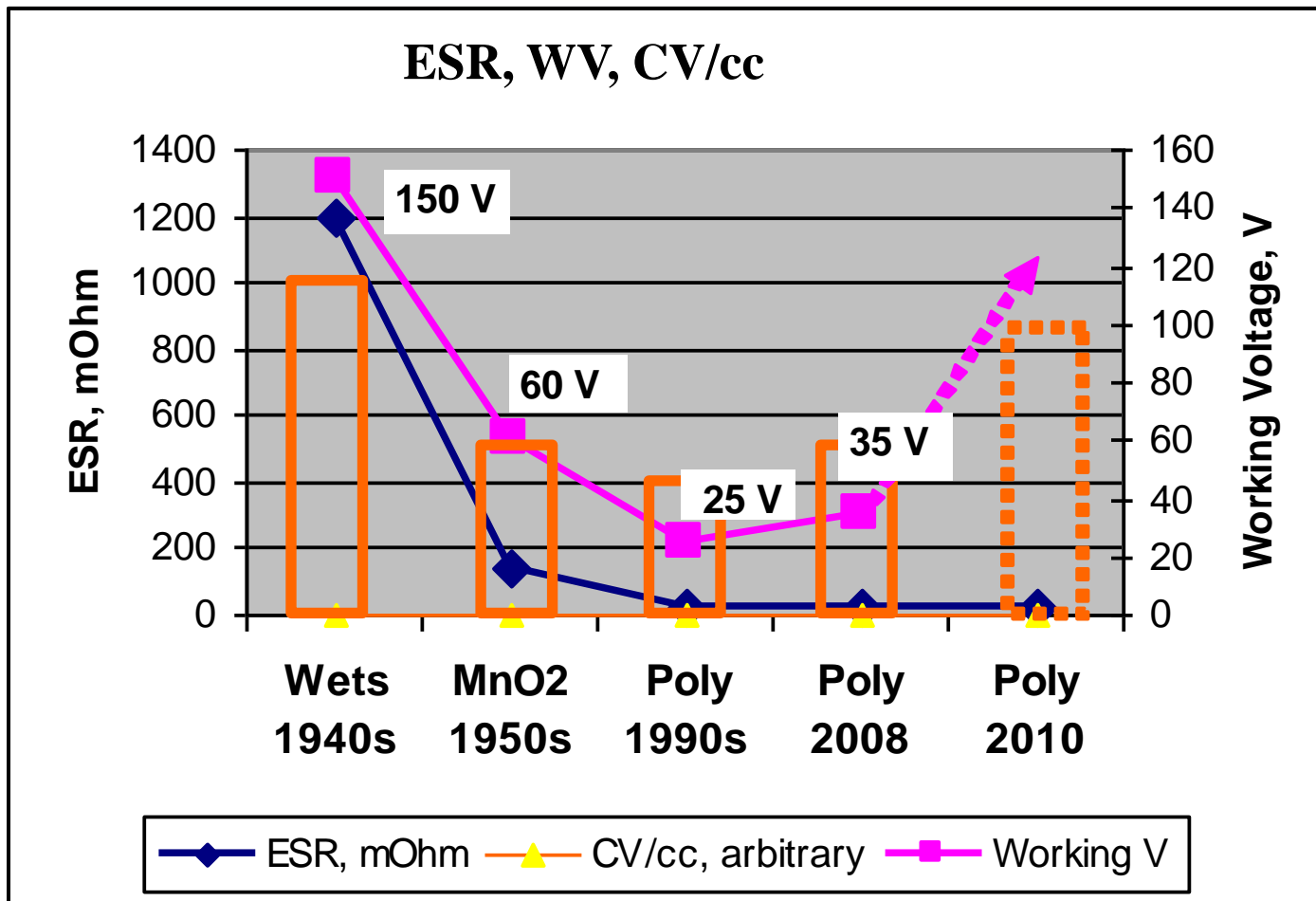
- In case of Slurry, the barrier on I/S interface is not pinned, it increases with voltage, which results in low current and Hi BDV at normal polarity.

MIS Model (Al-SiO₂-Si)

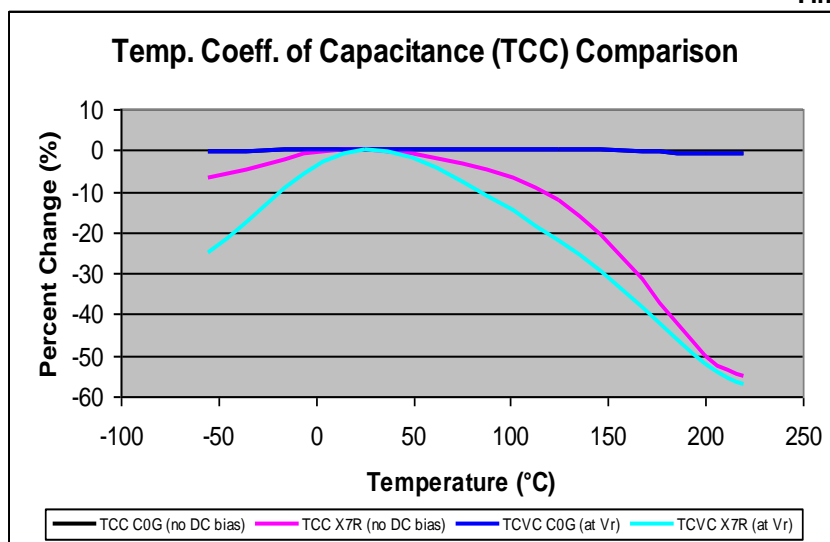
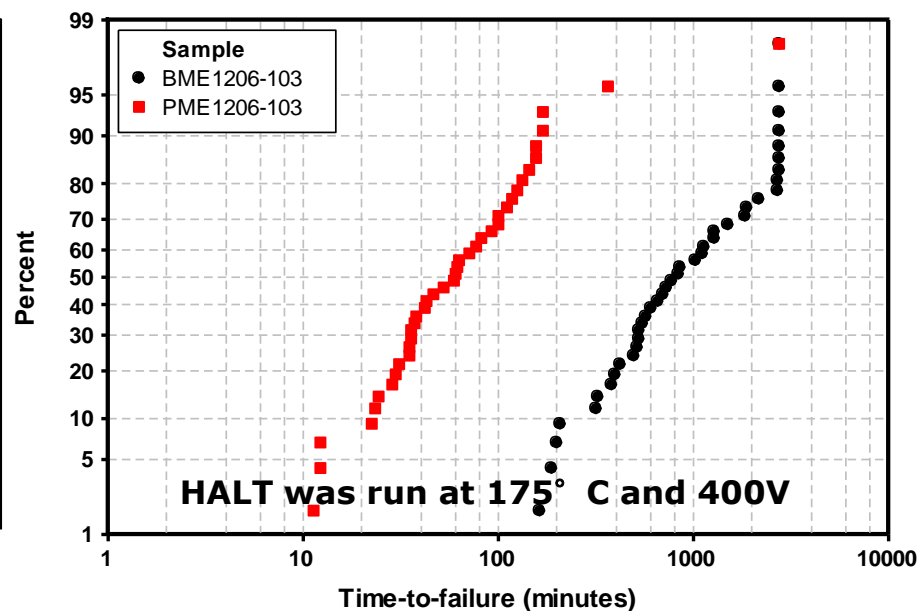
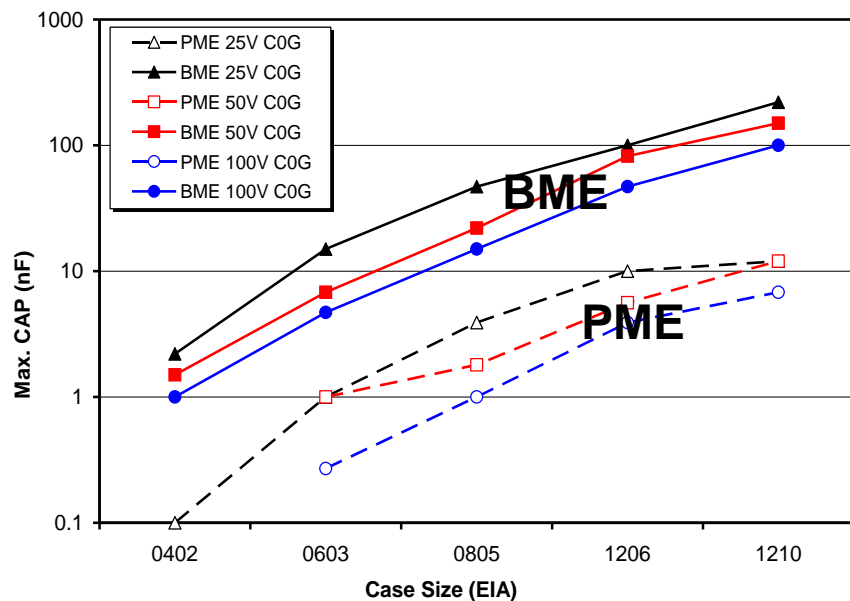


Surface charge on I/S interface with In-situ Poly

Future Possibilities



KEMET's new BME-C0G



High Temperature MLCC Offering

Characteristic	KEMET C0G	Industry 200°C X7R
Capacitance/Voltage Ratings	⊙	⊙
TCC (Temperature Stability)	✓	⊙
VCC (Voltage Stability)	✓	⊙
Aging Rate	✓	⊙
Piezoelectric Effects	✓	⊙
ESR/Q Factor Stability	✓	⊙
Insulation Resistance Stability	✓	⊙

High Temperature (200°C) Product Line

Description

- Surface Mount MLCC's and stacked capacitors capable of 200°C applications
- Surface mount chips with reliable BME C0G & PME X7R dielectrics featuring world class TCVC characteristics and high reliability.
- C0G SMD's that exceed X7R max cap at application temperatures.
- Sn plating for excellent solderability.

Applications:

- Bypass, filtering, decoupling capacitors

Markets

- Downhole Drilling
- Defense and Aerospace

